

SILICON TRANSISTOR 2SB1453

PNP SILICON EPITAXIAL POWER TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SB1453 is a power transistor that can directly drive from the IC output. This transistor is ideal for motor drivers and solenoid drivers in such as OA and FA equipment.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

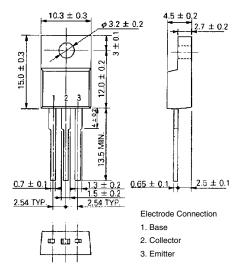
- High DC current amplifier ratio
 hFE ≥ 100 (VcE = -5 V, Ic = -0.5 A)
- Mold package that does not require an insulating board or insulation bushing

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{СВО}	-60	V
Collector to emitter voltage	VCEO	-60	V
Emitter to base voltage	V _{EBO}	-7.0	V
Collector current (DC)	Ic(DC)	-3.0	Α
Collector current (pulse)	Ic(pulse)*	-6.0	Α
Base current (DC)	I _{B(DC)}	-1.0	Α
Total power dissipation	P⊤ (Tc = 25°C)	25	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

^{*} PW \leq 10 ms, duty cycle \leq 50%

PACKAGE DRAWING (UNIT: mm)



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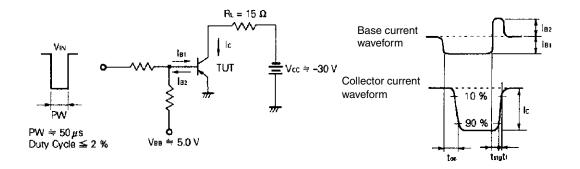


ELECTRICALS CHAPACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -60 V, IE = 0			-10	μΑ
DC current gain	h _{FE1} **	Vce = -5.0 V, Ic = -0.5 A	100		400	_
DC current gain	h _{FE2} **	Vce = -5 V, Ic = -3 A	20			_
Collector saturation voltage	V _{CE(sat)} **	Ic = -3.0 A, I _B = -300 mA			-1.0	٧
Base saturation voltage	V _{BE(sat)} **	Ic = -3.0 A, I _B = -300 mA			-2.0	٧
Gain bandwidth product	f⊤	Vce = -5.0 V, Ic = -0.5 A		5		MHz
Collector capacitance	Cob	VcB = −10 V, IE = 0, f = 1.0 MHz		80		pF
Turn-on time	ton	Ic = -2.0 A, IB1 = -IB2 = -200 mA, RL = 15 Ω , Vcc \cong -30 V Refer to the test circuit.		0.4		μs
Storage time	tstg			1.7		μs
Fall time	tf			0.5		μs

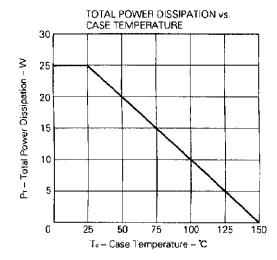
^{**} Pulse test PW \leq 350 μ s, duty cycle \leq 2%

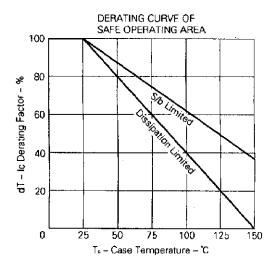
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

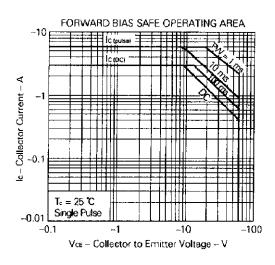


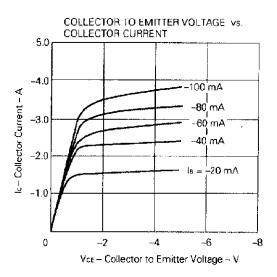


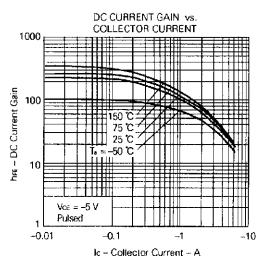
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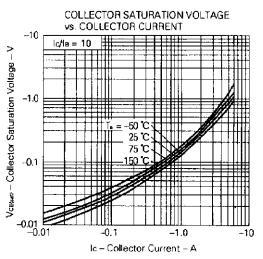








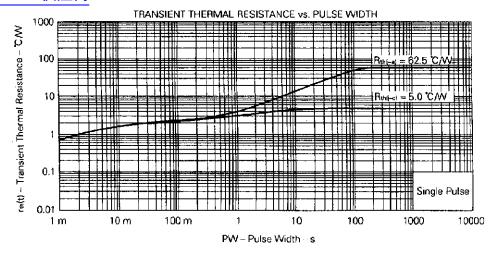


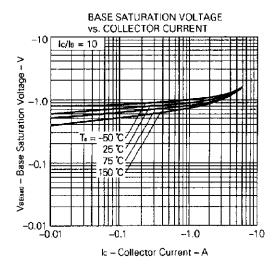


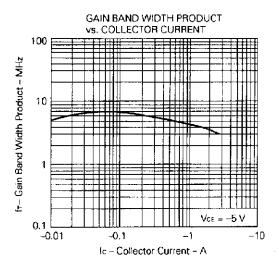
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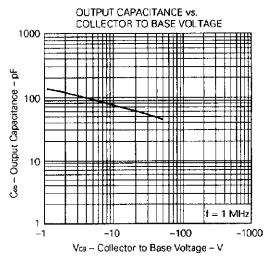


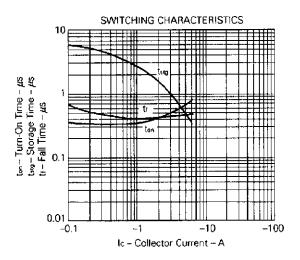
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